


[Home](#) ▶ [2N5886 \(#23491\)](#)

Products

- ▶ [Product Directory](#)
- ▶ [Applications Directory](#)
- ▶ [Parametric Search](#)

2N5886 (#23491)

Overview

Diagrams

| Electrical Rating | Symbol | Min | Typ | Max | Unit |
|---|---------------|-------|-----|--------|------|
| Collector to Emitter Saturation Voltage | $V_{CE(sat)}$ | | | 1.00 | V |
| DC Current Gain | HFE | 20.00 | | 100.00 | |

| Maximum Electrical Rating | Symbol | Min | Typ | Max | Unit |
|--|---------------|-----|-----|--------|------|
| Breakdown Voltage, Collector-Base (Emitter Open) | $V_{BR(CBO)}$ | | | 80.00 | V |
| Collector Current (dc) | I_C | | | 25.00 | A |
| Collector-Emitter Voltage (Base Open) | V_{CEO} | | | 80.00 | V |
| Emitter-Base Voltage (Collector Open) | V_{EBO} | | | 5.00 | V |
| Power Dissipation, Total | P_T | | | 200.00 | W |

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